

## Absolute Maximum Ratings

|                                                       |                                   |
|-------------------------------------------------------|-----------------------------------|
| V <sub>DD</sub> to GND .....                          | -0.3V to +6V                      |
| RS+, RS- to GND .....                                 | -0.3V to +40V                     |
| RS+ to RS- .....                                      | ±40V                              |
| OUT, SHDN to GND .....                                | -0.3V to (V <sub>DD</sub> + 0.3V) |
| Continuous Input Current (any pin) .....              | ±20mA                             |
| Continuous Power Dissipation (T <sub>A</sub> = +70°C) |                                   |
| WLP (derate 10.5mW/°C above +70°C) .....              | 840mW                             |
| SOT23 (derate 4.3mW/°C above +70°C) .....             | 347.8mW                           |

|                                         |                 |
|-----------------------------------------|-----------------|
| Operating Temperature Range .....       | -40°C to +125°C |
| Junction Temperature .....              | +150°C          |
| Storage Temperature Range .....         | -65°C to +150°C |
| Lead Temperature (soldering, 10s) ..... | +300°C          |
| Soldering Temperature (reflow) .....    | +260°C          |

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## Package Information

### 6 SOT23

| PACKAGE CODE                                   | U6+1, U6+1A             |
|------------------------------------------------|-------------------------|
| Outline Number                                 | <a href="#">21-0058</a> |
| Land Pattern Number                            | <a href="#">90-0175</a> |
| <b>Thermal Resistance, Single-Layer Board:</b> |                         |
| Junction to Ambient - $\theta_{JA}$ (C/W)      | N/A                     |
| Junction to Case - $\theta_{JC}$ (C/W)         | 80                      |
| <b>Thermal Resistance, Multi-Layer Board</b>   |                         |
| Junction to Ambient ( $\theta_{JA}$ ) (C/W)    | 115                     |
| Junction to Case ( $\theta_{JC}$ ) (C/W)       | 80                      |

### 6 WLP

| PACKAGE CODE                                 | W60A1+1                                        |
|----------------------------------------------|------------------------------------------------|
| Outline Number                               | <a href="#">21-0656</a>                        |
| Land Pattern Number                          | Refer to <a href="#">Application Note 1891</a> |
| <b>Thermal Resistance, Multi-Layer Board</b> |                                                |
| Junction to Ambient ( $\theta_{JA}$ ) (C/W)  | 95.15                                          |
| Junction to Case ( $\theta_{JC}$ ) (C/W)     | N/A                                            |

For the latest package outline information and land patterns (footprints), go to [www.maximintegrated.com/packages](http://www.maximintegrated.com/packages). Note that a "+", "#", or "-" in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

Package thermal resistances were obtained using the method described in JEDEC specification JESD51-7, using a four-layer board. For detailed information on package thermal considerations, refer to [www.maximintegrated.com/thermal-tutorial](http://www.maximintegrated.com/thermal-tutorial).

## Electrical Characteristics

( $V_{DD} = 3.3V$ ,  $V_{CM} = 12V$ ,  $V_{SENSE} = V_{FS}/2$ ,  $V_{FS} = (V_{DD} - V_{OH} - V_{OL})/\text{Gain}$ ,  $V_{SHDN} = V_{DD}$ ,  $R_L = 10k\Omega$  to GND,  $T_A = -40^\circ\text{C}$  to  $+125^\circ\text{C}$ , unless otherwise noted. Typical values are at  $T_A = +25^\circ\text{C}$ .) (Note 2)

| PARAMETER                              | SYMBOL                | CONDITIONS                                                            | MIN  | TYP      | MAX        | UNITS                     |
|----------------------------------------|-----------------------|-----------------------------------------------------------------------|------|----------|------------|---------------------------|
| <b>POWER SUPPLY</b>                    |                       |                                                                       |      |          |            |                           |
| Supply Voltage                         | $V_{DD}$              | Guaranteed by PSRR                                                    | 1.7  |          | 5.5        | V                         |
| Shutdown Supply Current                | $I_{SHDN}$            |                                                                       |      | 0.3      | 0.8        | $\mu\text{A}$             |
| Supply Current                         | $I_{DD}$              | $T_A = +25^\circ\text{C}$ , $R_L = \infty$                            |      | 21       | 31.2       | $\mu\text{A}$             |
|                                        |                       | $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$ , $R_L = \infty$ |      |          | 41.5       |                           |
| Power-Supply Rejection Ratio           | PSRR                  | $1.7V \leq V_{DD} \leq 5.5V$ , $V_{OUT} = 1V$                         | 100  | 110      |            | dB                        |
| Shutdown Voltage Low                   | $V_{IL}$              |                                                                       |      |          | 0.55       | V                         |
| Shutdown Voltage High                  | $V_{IH}$              |                                                                       | 1.3  |          |            | V                         |
| <b>DC CHARACTERISTICS</b>              |                       |                                                                       |      |          |            |                           |
| Input Common-Mode Voltage Range        | $V_{CM}$              | Guaranteed by CMRR                                                    | -0.1 |          | +36        | V                         |
| Common-Mode Rejection Ratio (Note 5)   | CMRR                  | $-0.1V \leq V_{CM} \leq +36V$ , $V_{CM} = RS-$                        | 91.3 | 140      |            | dB                        |
|                                        |                       | $+0.1V \leq V_{CM} \leq +36V$ , $V_{CM} = RS-$ (Note 7)               | 120  | 145      |            |                           |
| Input Bias Current                     | $I_{RS+}$ , $I_{RS-}$ |                                                                       |      | 2        | 80         | nA                        |
| Input Offset Current                   | $I_{OS}$              |                                                                       |      | 2        | 50         | nA                        |
| Input Offset Voltage (Note 3)          | $V_{OS}$              | MAX44284F ( $T_A = +25^\circ\text{C}$ )                               |      | $\pm 2$  | $\pm 10$   | $\mu\text{V}$             |
|                                        |                       | MAX44284F ( $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$ )    |      |          | $\pm 28$   |                           |
|                                        |                       | MAX44284H ( $T_A = +25^\circ\text{C}$ )                               |      | $\pm 2$  | $\pm 12$   |                           |
|                                        |                       | MAX44284H ( $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$ )    |      |          | $\pm 28$   |                           |
|                                        |                       | MAX44284W ( $T_A = +25^\circ\text{C}$ )                               |      | $\pm 10$ | $\pm 20.5$ |                           |
|                                        |                       | MAX44284W ( $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$ )    |      |          | $\pm 38$   |                           |
|                                        |                       | MAX44284E ( $T_A = +25^\circ\text{C}$ )                               |      | $\pm 15$ | $\pm 26$   |                           |
|                                        |                       | MAX44284E ( $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$ )    |      |          | $\pm 40$   |                           |
| Input Offset Voltage Temperature Drift | $TCV_{OS}$            |                                                                       |      | 50       |            | $\text{nV}^\circ\text{C}$ |
| Gain                                   | G                     | MAX44284F                                                             |      | 50       |            | V/V                       |
|                                        |                       | MAX44284H                                                             |      | 100      |            |                           |
|                                        |                       | MAX44284W                                                             |      | 200      |            |                           |
|                                        |                       | MAX44284E                                                             |      | 500      |            |                           |

**Electrical Characteristics (continued)**

( $V_{DD} = 3.3V$ ,  $V_{CM} = 12V$ ,  $V_{SENSE} = V_{FS}/2$ ,  $V_{FS} = (V_{DD} - V_{OH} - V_{OL})/\text{Gain}$ ,  $V_{SHDN} = V_{DD}$ ,  $R_L = 10k\Omega$  to GND,  $T_A = -40^\circ\text{C}$  to  $+125^\circ\text{C}$ , unless otherwise noted. Typical values are at  $T_A = +25^\circ\text{C}$ .) (Note 2)

| PARAMETER                      | SYMBOL     | CONDITIONS                                                            | MIN | TYP  | MAX  | UNITS                        |
|--------------------------------|------------|-----------------------------------------------------------------------|-----|------|------|------------------------------|
| Gain Error (Note 4)            | GE         | MAX44284F ( $T_A = +25^\circ\text{C}$ )                               |     | 0.05 | 0.15 | %                            |
|                                |            | MAX44284F<br>( $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$ ) |     |      | 0.20 |                              |
|                                |            | MAX44284H ( $T_A = +25^\circ\text{C}$ )                               |     | 0.05 | 0.15 |                              |
|                                |            | MAX44284H<br>( $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$ ) |     |      | 0.26 |                              |
|                                |            | MAX44284W ( $T_A = +25^\circ\text{C}$ )                               |     | 0.05 | 0.15 |                              |
|                                |            | MAX44284W<br>( $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$ ) |     |      | 0.35 |                              |
|                                |            | MAX44284E ( $T_A = +25^\circ\text{C}$ )                               |     | 0.05 | 0.16 |                              |
|                                |            | MAX44284E<br>( $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$ ) |     |      | 0.39 |                              |
| Output Voltage High            | $V_{OH}$   | $V_{OH} = V_{DD} - V_{OUT}$ ,<br>$R_L = 10k\Omega$ to GND             |     | 25   | 35   | mV                           |
|                                |            | $I_{SOURCE} = 100\mu\text{A}$                                         |     |      | 20   |                              |
| Output Voltage Low             | $V_{OL}$   | No load                                                               |     | 0.3  | 1    | mV                           |
|                                |            | $I_{SINK} = 100\mu\text{A}$                                           |     |      | 20   |                              |
| Input Differential Impedance   |            |                                                                       |     | 6    |      | $M\Omega$                    |
| Output Impedance               |            |                                                                       |     | 200  |      | $m\Omega$                    |
| <b>AC CHARACTERISTICS</b>      |            |                                                                       |     |      |      |                              |
| Small-Signal Bandwidth         | $BW_{3dB}$ | MAX44284F                                                             |     | 3    |      | kHz                          |
|                                |            | MAX44284H                                                             |     | 1.8  |      |                              |
|                                |            | MAX44284W                                                             |     | 1    |      |                              |
|                                |            | MAX44284E                                                             |     | 0.4  |      |                              |
| Input Voltage-Noise Density    | $e_n$      | $f = 1\text{kHz}$                                                     |     | 150  |      | $\text{nV}/\sqrt{\text{Hz}}$ |
| AC Common-Mode Rejection Ratio | AC CMRR    | $f = 10\text{kHz}$ , 600mV <sub>P-P</sub> sinusoidal waveform         |     | 80   |      | dB                           |

**Electrical Characteristics (continued)**

( $V_{DD} = 3.3V$ ,  $V_{CM} = 12V$ ,  $V_{SENSE} = V_{FS}/2$ ,  $V_{FS} = (V_{DD} - V_{OH} - V_{OL})/\text{Gain}$ ,  $V_{SHDN} = V_{DD}$ ,  $R_L = 10k\Omega$  to GND,  $T_A = -40^\circ\text{C}$  to  $+125^\circ\text{C}$ , unless otherwise noted. Typical values are at  $T_A = +25^\circ\text{C}$ .) (Note 2)

| PARAMETER       | SYMBOL | CONDITIONS                                                       | MIN | TYP  | MAX | UNITS         |
|-----------------|--------|------------------------------------------------------------------|-----|------|-----|---------------|
| Settling Time   | $t_s$  | $V_{OUT}$ from 250mV to 2.5V, Gain = 50, within 12-bit accuracy  |     | 1500 |     | $\mu\text{s}$ |
|                 |        | $V_{OUT}$ from 250mV to 2.5V, Gain = 100, within 12-bit accuracy |     | 1500 |     |               |
|                 |        | $V_{OUT}$ from 250mV to 2.5V, Gain = 200, within 12-bit accuracy |     | 1800 |     |               |
|                 |        | $V_{OUT}$ from 250mV to 2.5V, Gain = 500, within 12-bit accuracy |     | 4000 |     |               |
| Capacitive Load | $C_L$  | $R_{ISO} = 0\Omega$                                              |     | 500  |     | pF            |
|                 |        | $R_{ISO} = 20\Omega$                                             |     | 2200 |     |               |

**Note 2:** All devices are 100% production tested at  $T_A = +25^\circ\text{C}$ . All temperature limits are guaranteed by design.

**Note 3:**  $V_{OS}$  is calculated by applying two values of  $V_{SENSE}$  (10% of full-scale range to 90% of full-scale range).

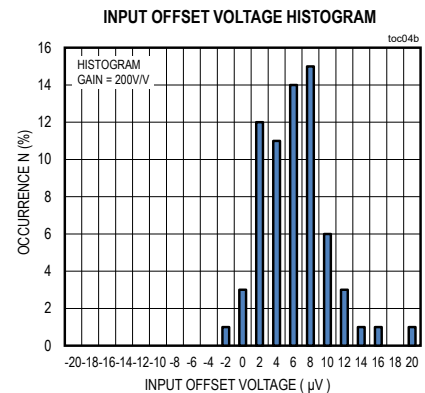
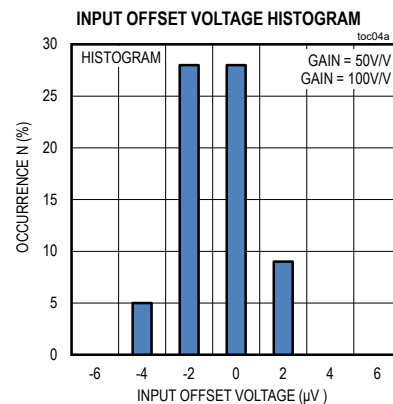
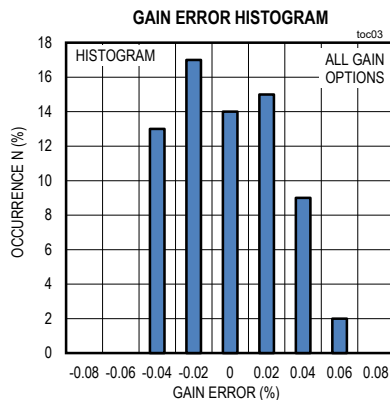
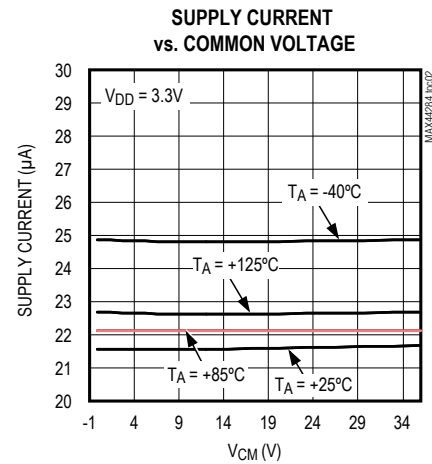
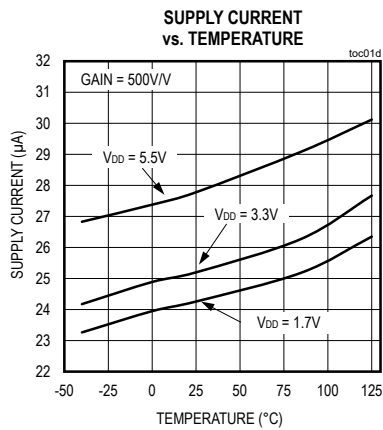
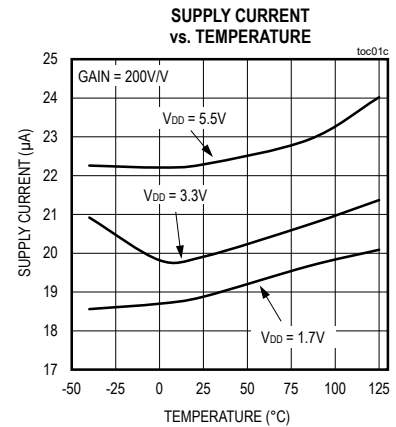
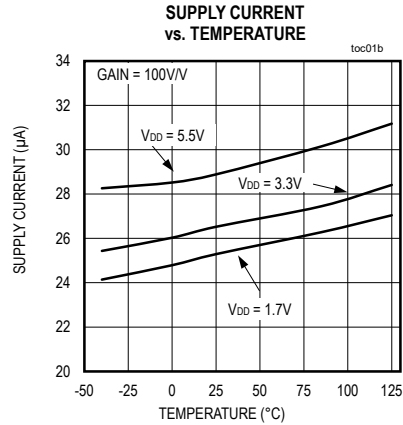
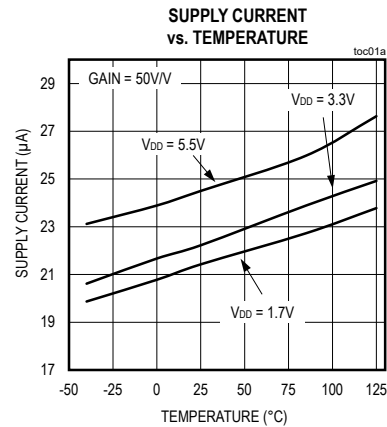
**Note 4:** Gain error is calculated by applying two values of  $V_{SENSE}$  (10% of full-scale range to 90% of full-scale range) and calculating the error of the slope vs. the ideal.

**Note 5:** CMRR measurement is done at  $V_{OUT} = V_{DD}/2$  condition.

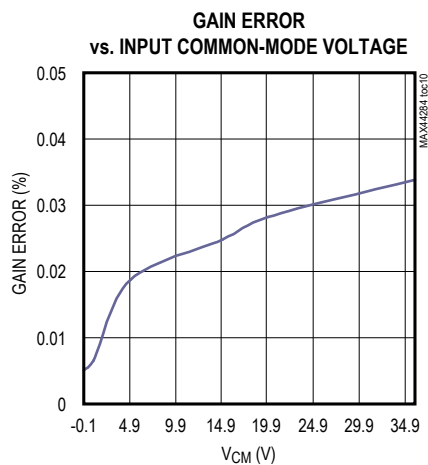
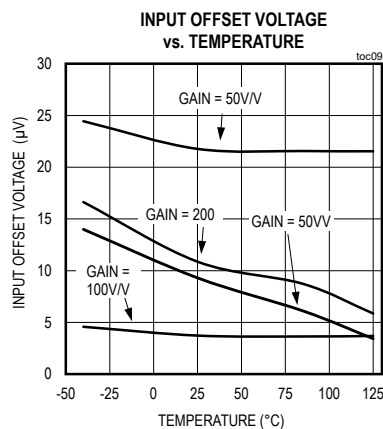
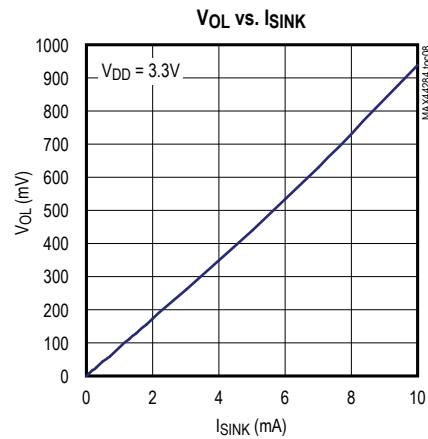
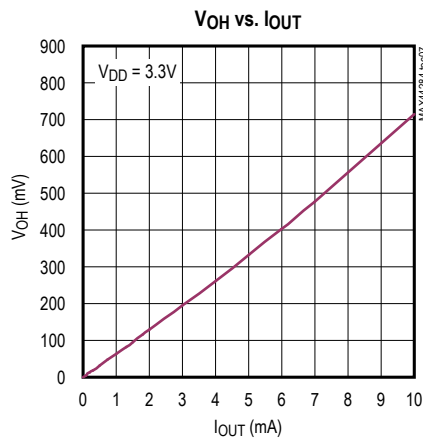
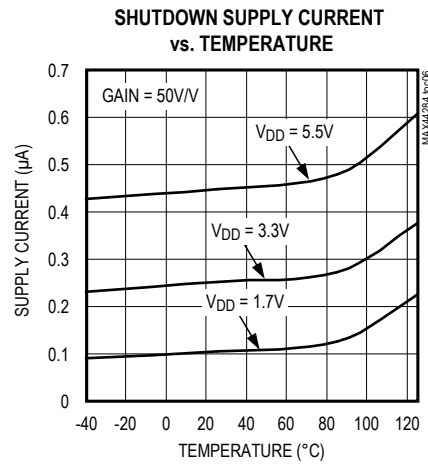
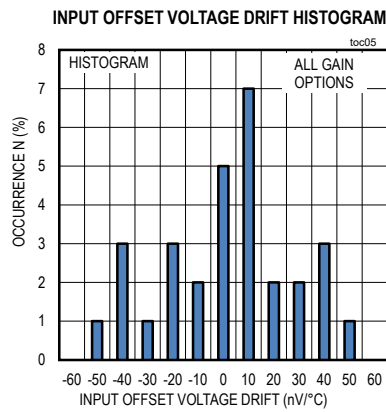
**Note 6:** PSRR measurement is done at  $V_{OUT} = 1V$  condition.

**Note 7:** Parameter is guaranteed by design.

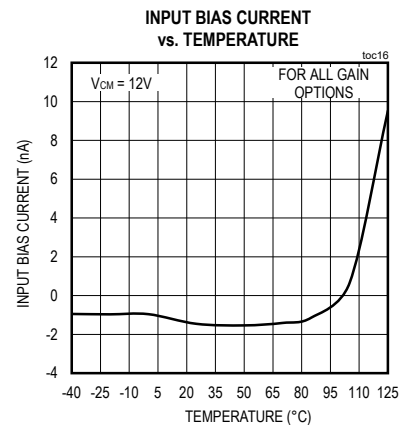
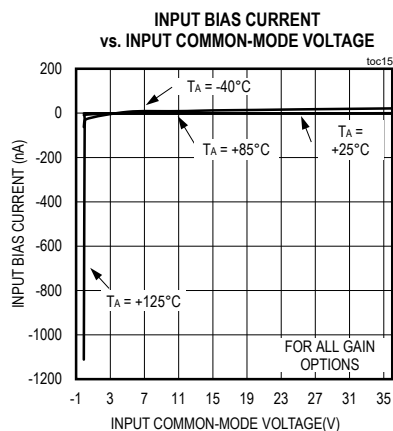
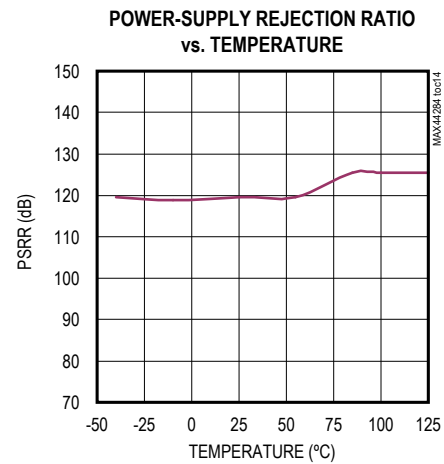
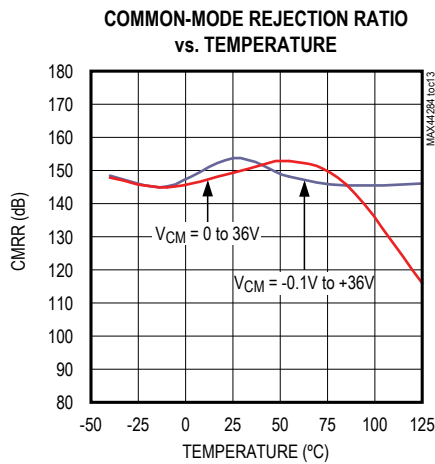
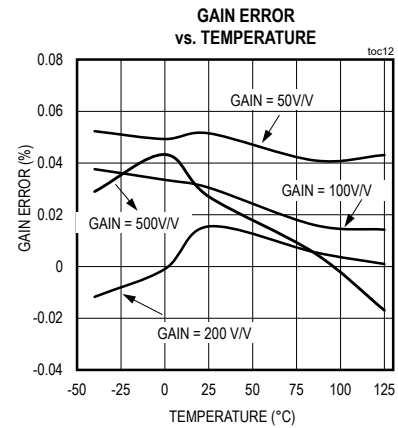
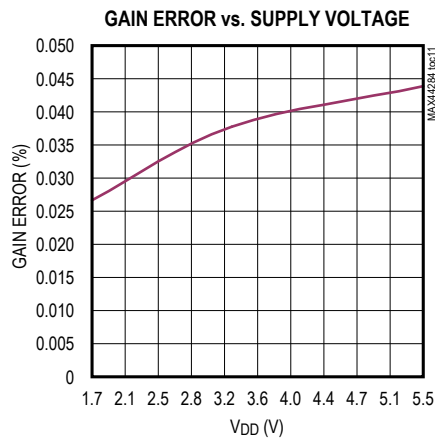
## Typical Operating Characteristics

(T<sub>A</sub> = +25°C, unless otherwise noted.)

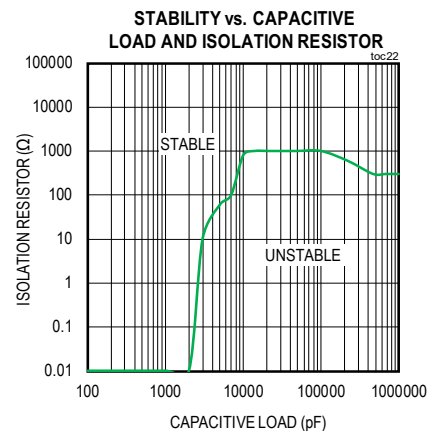
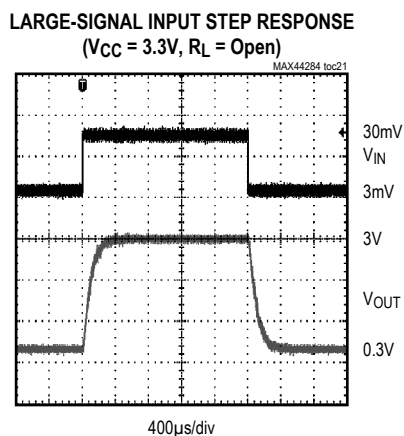
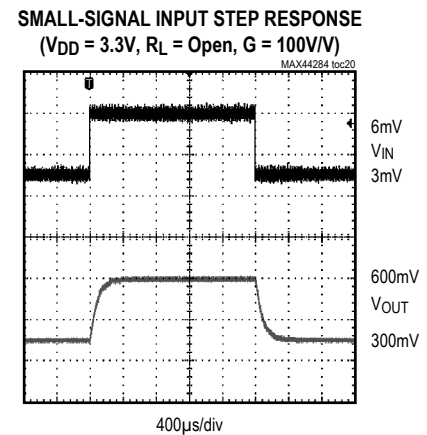
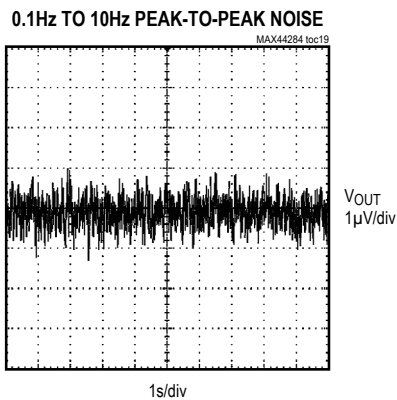
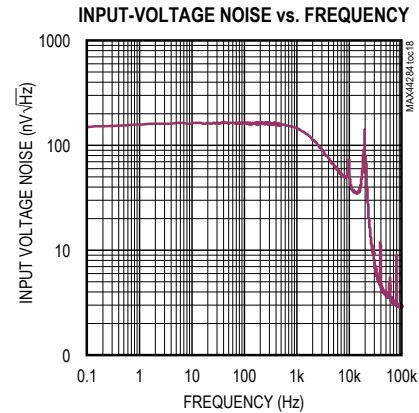
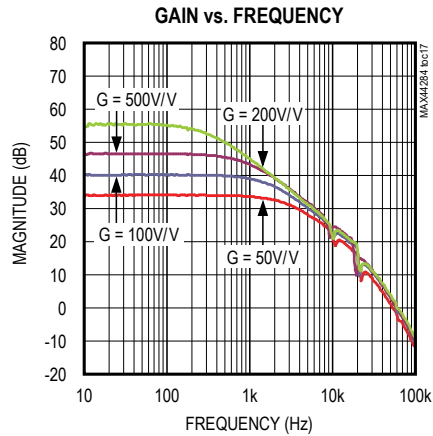
## Typical Operating Characteristics (continued)

(T<sub>A</sub> = +25°C, unless otherwise noted.)

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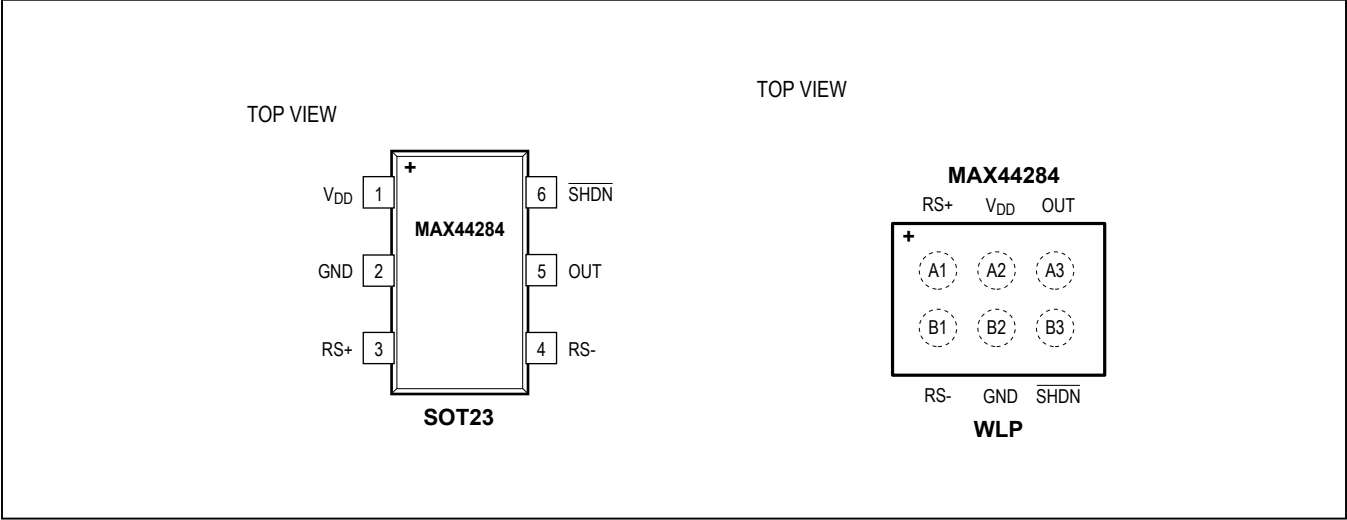
(T<sub>A</sub> = +25°C, unless otherwise noted.)



MAX44284

36V, Input Common-Mode, High-Precision,  
Low-Power Current-Sense Amplifier

Pin Configurations



Pin Description

| PIN   | BUMP | NAME            | FUNCTION                                                                                                                                  |
|-------|------|-----------------|-------------------------------------------------------------------------------------------------------------------------------------------|
| SOT23 | WLP  |                 |                                                                                                                                           |
| 1     | A2   | V <sub>DD</sub> | Power-Supply Voltage Input. Bypass V <sub>DD</sub> to GND with 0.1μF and 4.7μF capacitors in parallel as close as possible to the device. |
| 2     | B2   | GND             | Ground                                                                                                                                    |
| 3     | A1   | RS+             | External Sense Resistor Power-Side Connection                                                                                             |
| 4     | B1   | RS-             | External Sense Resistor Load-Side Connection                                                                                              |
| 5     | A3   | OUT             | Output Voltage. V <sub>OUT</sub> is proportional to V <sub>SENSE</sub> = V <sub>RS+</sub> - V <sub>RS-</sub> .                            |
| 6     | B3   | SHDN            | Active-Low Shutdown Input. Connect to V <sub>DD</sub> for normal operation.                                                               |

## Detailed Description

The MAX44284 family features a single-supply, high-accuracy unidirectional, current-sense amplifier in various gain options and a -0.1V to 36V input common-mode range that is independent of supply voltage ( $V_{DD}$ ). The MAX44284 is ideal for many battery-powered, handheld devices because it uses only maximum 31.2μA quiescent supply current to extend battery life. The device's low input offset voltage, tight gain error, and low temperature drift characteristics allow the use of small-sense resistors for current measurements to improve power-supply conversion efficiency and accuracy of measurements. This feature allows monitoring of power-supply load current even if the rail is shorted to ground. High-side current monitoring does not interfere with the ground path of the load being measured, making the IC particularly useful in a wide range of high-reliability systems.

Because of its extended common-mode range below ground, this part can also be used as a low-side current sensing element.

## Shutdown

The MAX44284 features active-low logic shutdown input to reduce the supply current. Drive  $\overline{\text{SHDN}}$  high for normal operation. Drive  $\overline{\text{SHDN}}$  low to place the device in shutdown mode. In shutdown mode, the supply current drawn from the  $V_{DD}$  is less than 1μA (max).

## Precision

The MAX44284 uses capacitive-coupled Instrumentation amplifier architecture that enables the part to achieve over the top common-mode voltage ranges, high power efficiency, high gain accuracy, and low-power design.

## Low Offset Voltage and Low Gain Error

The MAX44284 utilizes Capacitive-Coupled Chopper Instrumentation Amplifier (CCIA) architecture to achieve a low-input offset voltage of less than 10μA. These techniques also enable extremely low-input offset voltage drift over time and temperature to 50nV/°C. The precision  $V_{OS}$  specification allows accurate current measurements with lower values of current-sense resistors, thus reducing

power dissipation in battery-powered systems, as well as load regulation issues in low-voltage DC power supplies.

Working with error tolerances with very few internal blocks in this architecture is instrumental in achieving a gain error of less than 0.20% over the entire temperature range of -40°C to +125°C.

## Applications Information

### Input Differential Signal Range

The MAX44284's input structure is optimized for sensing small differential signals as low as 3.4mV full scale ( $V_{FS}$ ) for high efficiency with lowest power dissipation in the sense resistor, or 110mV full scale for high dynamic range. The input differential signal range is determined by the following equation for the MAX44284 family.

$$V_{(\text{SENSE RANGE})} = \frac{V_{DD}}{\text{GAIN}}$$

The input differential voltage range is estimated for  $V_{DD}$  from 1.7V to 5.5V for different gain values of the MAX44284 as shown in [Table 1](#).

Ideally, the maximum load current develops the full-scale sense voltage across the current-sense resistor. Choose the gain needed to yield the maximum output voltage required for the application:

$$V_{OUT} = \text{GAIN} \times V_{SENSE}$$

## Choosing the Sense Resistor

### Voltage Loss

A high  $R_{SENSE}$  value causes the power-source voltage to drop due to IR loss. For minimal voltage loss, use the lowest  $R_{SENSE}$  value.

### Accuracy

Use the below linear equation to calculate total error:

$$V_{OUT} = (\text{GAIN} \pm \text{GE}) \times V_{SENSE} \pm (\text{GAIN} \times V_{OS})$$

**Table 1.  $V_{SENSE}$  Input Range**

| PART      | GAIN (V/V) | $V_{SENSE}$ RANGE (mV) with $V_{DD}$ (1.7V) | $V_{SENSE}$ RANGE (mV) with $V_{DD}$ (5.5V) |
|-----------|------------|---------------------------------------------|---------------------------------------------|
| MAX44284F | 50         | 34                                          | 110                                         |
| MAX44284H | 100        | 17                                          | 55                                          |
| MAX44284W | 200        | 8.5                                         | 27.5                                        |
| MAX44284E | 500        | 3.4                                         | 11                                          |

A high  $R_{SENSE}$  value allows lower currents to be measured more accurately because offsets are less significant when the sense voltage is larger. Note that the tolerance and temperature coefficient of the chosen resistors directly affect the precision of any measurement system. For best performance, select  $R_{SENSE}$  to provide approximately maximum input differential sense voltage of 110mV (MAX44284F) or 55mV (MAX44284H) or 27.5mV (MAX44284W) or 11mV (MAX44284E) of sense voltage for the full-scale current in each application. Sense resistors of 5mΩ to 100mΩ are available with 1% accuracy or better.

### Efficiency and Power Dissipation

At high current levels, the  $I^2R$  losses in  $R_{SENSE}$  can be significant. This should be taken into consideration when choosing the resistor value and its power dissipation (wattage) rating. The sense resistor's value will drift if it is allowed to heat up excessively. The precision  $V_{OS}$  of the MAX44284 allows the use of small sense resistors to reduce power dissipation and reduce hot spots.

### Kelvin Connections

Because of the high currents that may flow through  $R_{SENSE}$  based on the application, take care to eliminate solder and parasitic trace resistance from causing errors in the sense voltage. Either use a four-terminal current-sense resistor or use Kelvin (force and sense) PCB layout techniques.

### Input Filtering

Some applications of current-sense amplifiers need to measure currents accurately even in the presence of both differential and common-mode ripple, as well as a wide variety of input transient conditions.

The MAX44284 allows two methods of filtering to help improve performance in the presence of input common-mode voltage and input differential voltage transients. [Figure 1](#) shows a differential input filter. The capacitor  $C_{IN}$  across  $RS+$  and  $RS-$  along with the resistor  $R_{IN}$  helps filter against input differential voltages and prevents them from reaching the MAX44284. The corner frequency of this filter is determined by the choice of  $R_{IN}$ ,  $C_{IN}$ . [Figure 2](#) shows a common-mode input filter. The choice of capacitance depends on corner frequency after  $R_{IN}$  is chosen. In case of mismatch or error in application design, an

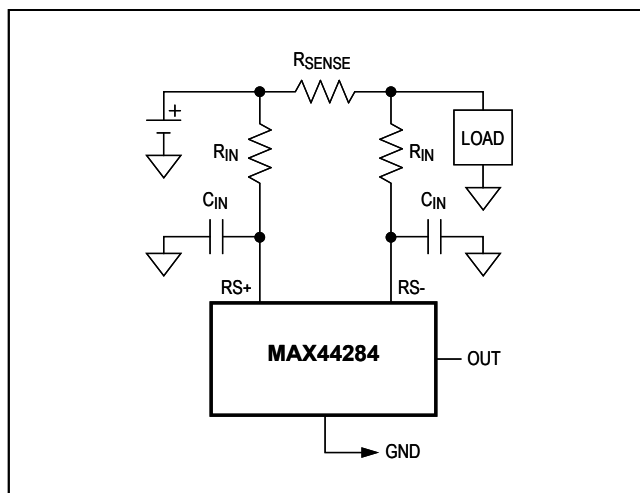


Figure 1. Differential Input Filtering

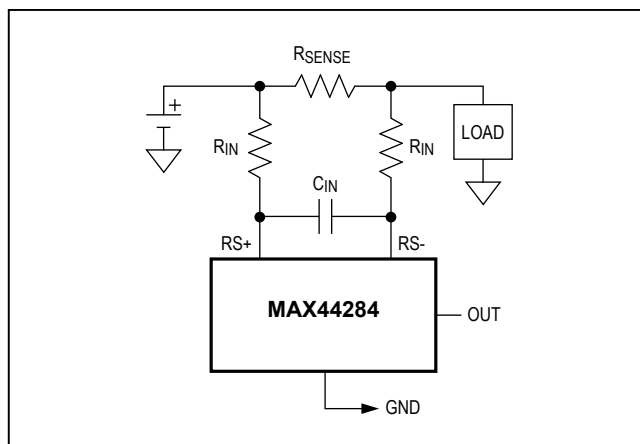


Figure 2. Input Common-Mode Filtering

additional DC error is accumulated as offset voltage and increased gain error.

$$V_{OS} = (R_{IN} \times I_{OFFSET}) + (DR_{IN} \times I_{BIAS})$$

$DR_{IN}$  is the resistance mismatch in  $R_{IN}$  at  $RS+$  and  $RS-$ . If  $DR_{IN}$  is too small, its effect can be neglected. Since  $I_{OFFSET}$  of the MAX44284 is smaller than 2nA, and if we want to make sure  $V_{OS}$  is lesser than 1μV range, choosing

$$R_{IN} < (V_{OS} \div I_{OFFSET})$$

For gain error, it depends on its input impedance and  $R_{IN}$ .

$$\text{GainError} = \frac{-R_{IN}}{2 \times Z_{IN}}$$

Avoid additional gain error shift due to the effect of  $R_{IN}$ . For gain error, the MAX44284 is 0.15%. If the margin of additional effect of  $R_{IN}$  results in a gain error shift of less than 0.02%, then:

$$R_{IN} < \frac{0.02\%}{2 \times Z_{IN}} = 600\Omega$$

So  $R_{IN}$  can be chosen  $\leq 500\Omega$ .

### Output Filtering

The internal architecture of the MAX44284 suppresses the DC offset, 1/f noise, and accumulates at higher frequencies so that they can be filtered out. Hence, minute AC disturbances can be observed at 10kHz and 20kHz. It is recommended to add an output filter after the MAX44284 to avoid noise and unwanted frequency disturbances at the output with 4kHz -3dB  $f_c$  (see [Figure 3](#)).

(Suggested values of C and R: 22nF and 1.8k $\Omega$ , respectively.)

Note that load capacitance greater than approximately 2nF may cause instability unless a series resistor is present to help isolate the capacitor from the amplifier output. Output stability with different values of load capacitor and isolation resistor is shown in TOC22 of the [Typical Operating Characteristics](#).

### Bidirectional Application

Battery-powered systems may require a precise bidirectional current-sense amplifier to accurately monitor the battery's charge and discharge currents. Measurements of the two separate outputs with respect to GND yield an accurate measure of the charge and discharge currents, respectively ([Figure 4](#)).

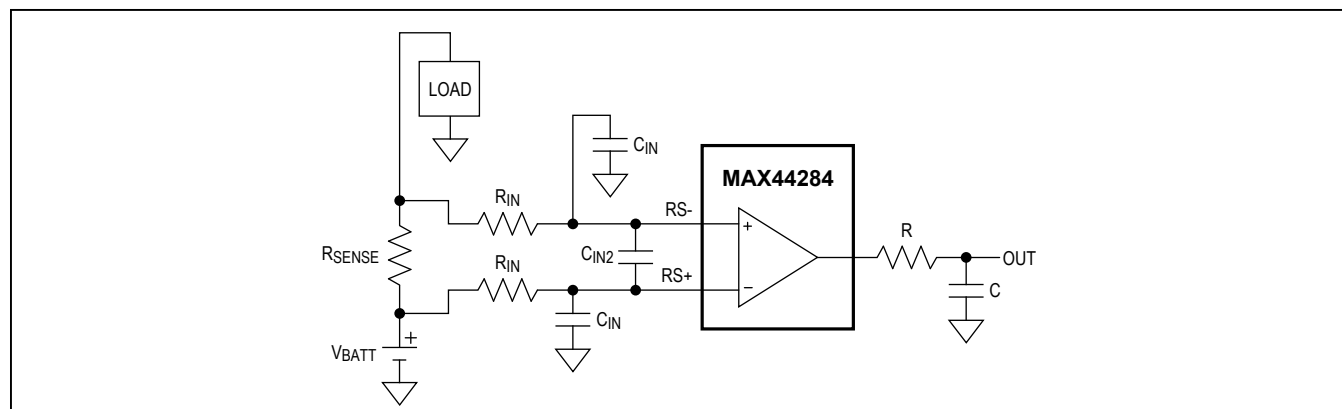


Figure 3. Filtering

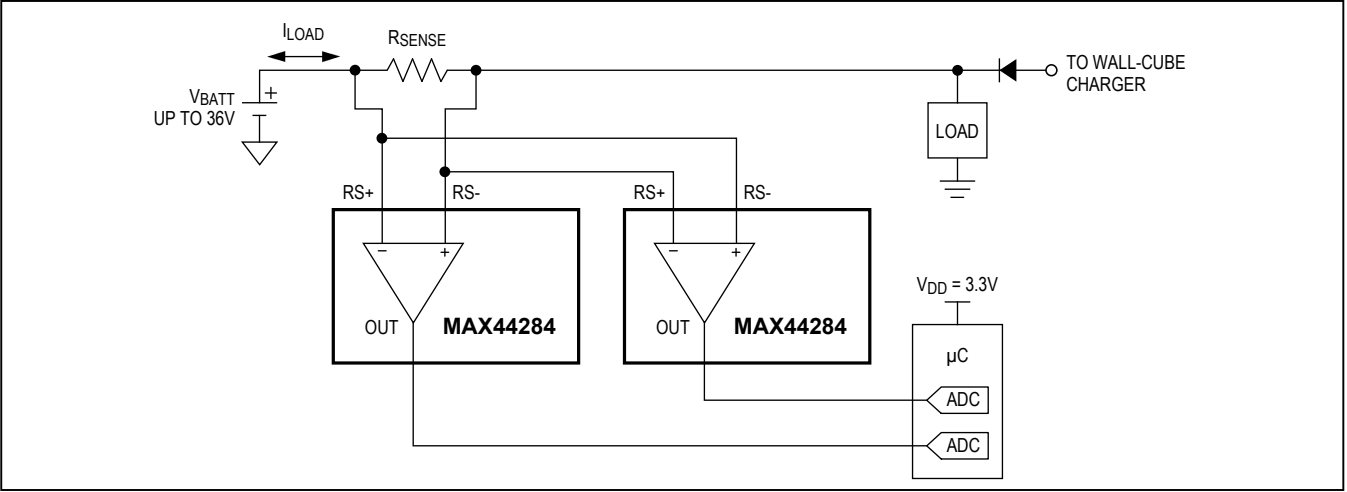


Figure 4. Bidirectional Application

Ordering Information

| PART              | GAIN (V/V) | TEMP RANGE      | PIN-PACKAGE | TOP MARK |
|-------------------|------------|-----------------|-------------|----------|
| MAX44284FAWT+     | 50         | -40°C to +125°C | 6 WLP       | +CX      |
| MAX44284FAUT+     | 50         | -40°C to +125°C | 6 SOT23     | +ACSF    |
| MAX44284FAUT/V+T* | 50         | -40°C to +125°C | 6 SOT23     | —        |
| MAX44284HAWT+     | 100        | -40°C to +125°C | 6 WLP       | +CY      |
| MAX44284HAUT+     | 100        | -40°C to +125°C | 6 SOT23     | +ACSG    |
| MAX44284WAWT+     | 200        | -40°C to +125°C | 6 WLP       | +CZ      |
| MAX44284WAUT+     | 200        | -40°C to +125°C | 6 SOT23     | +ACSH    |
| MAX44284EAWT+     | 500        | -40°C to +125°C | 6 WLP       | +DA      |
| MAX44284EAUT+     | 500        | -40°C to +125°C | 6 SOT23     | +ACSI    |

+Denotes a lead(Pb)-free/RoHS-compliant package

\*Future product—contact factory for availability.

Chip Information

PROCESS: BiCMOS

## Revision History

| REVISION NUMBER | REVISION DATE | DESCRIPTION                                                                                | PAGES CHANGED |
|-----------------|---------------|--------------------------------------------------------------------------------------------|---------------|
| 0               | 12/13         | Initial release                                                                            | —             |
| 1               | 5/14          | Updated <i>Typical Operating Characteristics</i> and the <i>Ordering Information</i>       | 8, 13         |
| 2               | 6/14          | Corrected <i>General Description</i> and updated <i>Electrical Characteristics</i> globals | 1–4           |
| 3               | 9/14          | Released MAX44284E and updated the <i>Electrical Characteristics</i>                       | 3, 13         |
| 4               | 1/15          | Revised <i>Benefits and Features</i> section                                               | 1             |
| 5               | 11/17         | Corrected typo in <i>Output Filtering</i> section                                          | 12            |
| 6               | 6/18          | Updated TOC22                                                                              | 8             |
| 7               | 7/18          | Updated <i>Ordering Information</i> table                                                  | 13            |
| 8               | 8/18          | Updated <i>Package Information</i> section and <i>Typical Operating Characteristics</i>    | 2, 8          |
| 9               | 5/19          | Updated <i>Typical Operating Characteristics</i> and <i>Output Filtering</i> section       | 9, 13         |

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